

General Description

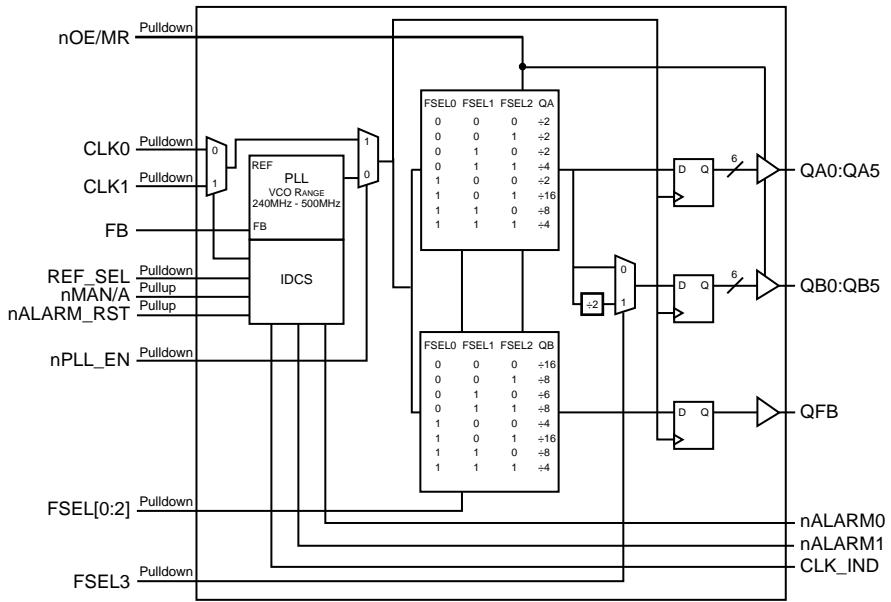
The 879893 is a PLL clock driver designed specifically for redundant clock tree designs. The device receives two LVCMOS/LVTTL clock signals from which it generates 12 new LVCMOS/LVTTL clock outputs. External PLL feedback is used to also provide zero delay buffer performance.

The 879893 Intelligent Dynamic Clock Switch (IDCS) circuit continuously monitors both input CLK signals. Upon detection of a failure (CLK stuck HIGH or LOW for at least 1 period), the nALARM for that CLK will be latched (LOW). If that CLK is the primary clock, the IDCS will switch to the good secondary clock and phase/frequency alignment will occur with minimal output phase disturbance.

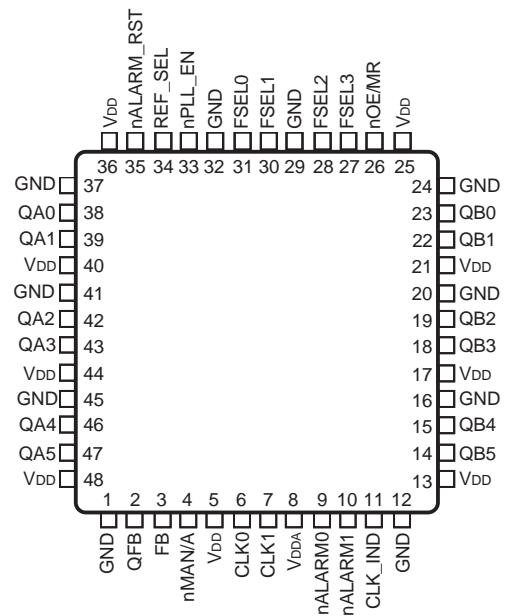
Features

- Twelve LVCMOS/LVTTL outputs (two banks of six outputs); One QFB feedback clock output
- Selectable CLK0 or CLK1 LVCMOS/LVTTL clock inputs
- CLK0, CLK1 supports the following input types: LVCMOS, LVTTL
- Automatically detects clock failure
- IDCS on-chip intelligent dynamic clock switch
- Maximum output frequency: 200MHz
- Output skew: 50ps (maximum), within bank
- Cycle-to-cycle (FSEL3=0, $V_{DD}=3.3V\pm5\%$): 150ps (maximum)
- Smooth output phase transition during clock fail-over switch
- Full 3.3V or 2.5V supply modes
- -40°C to 85°C ambient operating temperature
- Available in lead-free (RoHS 6) package
- **For functional replacement part use 87973i**

Simplified Block Diagram



Pin Assignment



879893

48-Lead LQFP
7mm x 7mm x 1.4mm package body
Y Package
Top View

Block Diagram

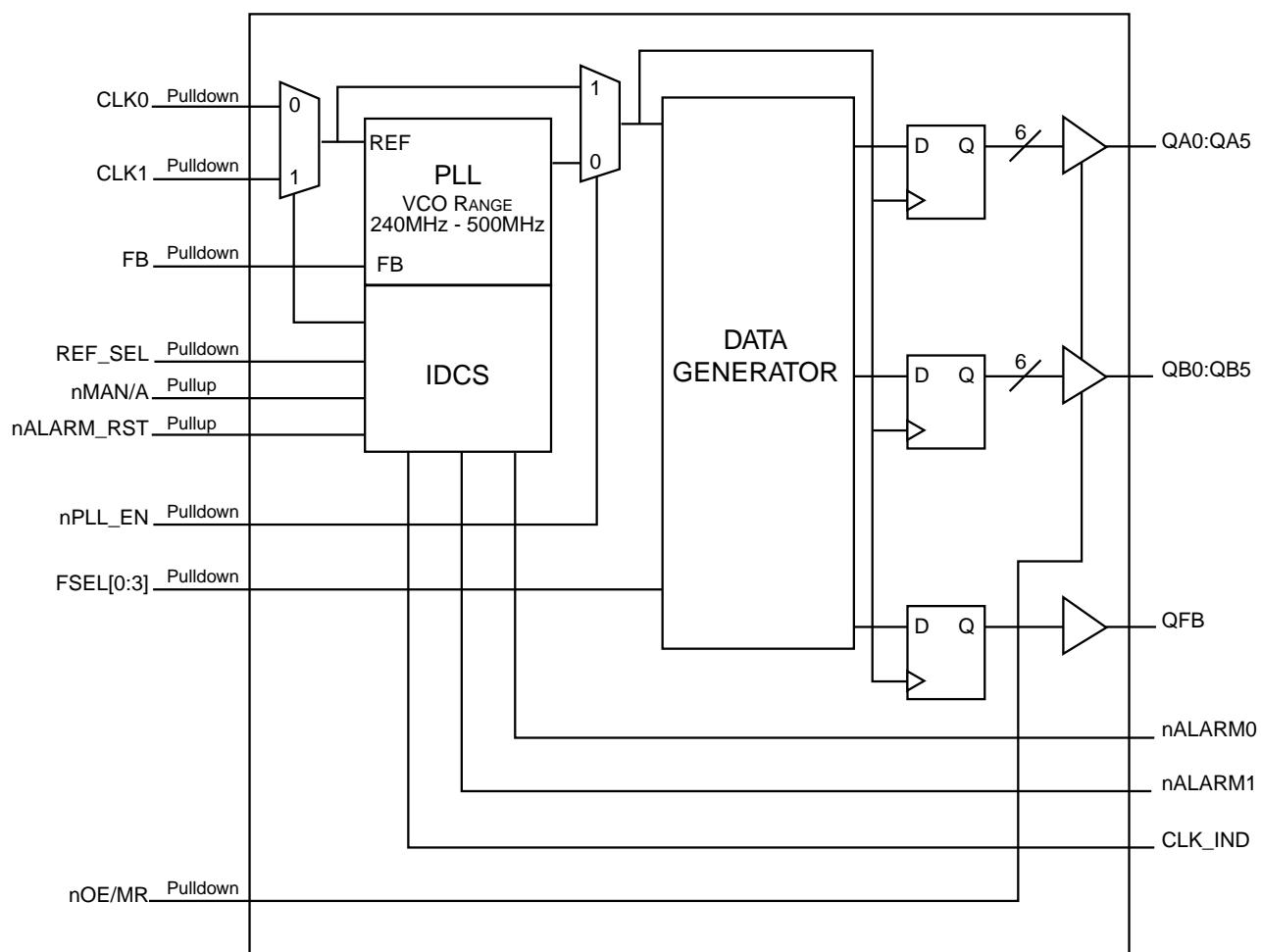


Table 1. Pin Descriptions

Number	Name	Type	Description
1, 12, 16, 20, 29, 32, 37, 41, 45	GND	Power	Power supply ground.
2	QFB	Output	Clock feedback output. LVCMOS / LVTTL interface levels.
3	FB	Input	Pulldown
4	nMAN/A	Input	Pullup
5, 13, 17, 21, 25, 36, 40, 44, 48	V _{DD}	Power	Core supply pins.
6, 7	CLK0, CLK1	Input	Pulldown
8	V _{DDA}	Power	Analog supply pin.
9	nALARM0	Output	When LOW, indicates clock failure on CLK0. LVCMOS / LVTTL interface levels.
10	nALARM1	Output	When LOW, indicates clock failure on CLK1. LVCMOS / LVTTL interface levels.
11	CLK_IND	Output	Indicates currently selected input reference clock. When LOW, CLK0 is the reference clock. When HIGH, CLK1 is the reference clock. LVCMOS / LVTTL interface levels.
14, 15, 18, 19, 22, 23	QB5, QB4, QB3, QB2, QB1, QB0	Output	Single-ended Bank B clock outputs. LVCMOS/LVTTL interface levels.
26	nOE/MR	Input	Pulldown
27, 28, 30, 31	FSEL3, FSEL2, FSEL1, FSEL0	Input	Pulldown
33	nPLL_EN	Input	Pulldown
34	REF_SEL	Input	Pulldown
35	nALARM_RST	Input	Pullup
38, 39 42, 43, 46, 47	QA0, QA1, QA2, QA3, QA4, QA5	Output	Single-ended Bank A clock outputs. LVCMOS/LVTTL interface levels.

NOTE: *Pullup* and *Pulldown* refer to internal input resistors. See Table 2, *Pin Characteristics*, for typical values.

Table 2. Pin Characteristics

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
C_{IN}	Input Capacitance		4			pF
C_{PD}	Power Dissipation Capacitance	$V_{DD} = 3.465V$		9		pF
		$V_{DD} = 2.625V$		9		pF
R_{PULLUP}	Input Pullup Resistor		51			k Ω
$R_{PULLDOWN}$	Input Pulldown Resistor		51			k Ω
R_{OUT}	Output Impedance		14			Ω

Function Tables**Table 3. Clock Frequency Function Table**

Inputs				f_{REF} Range (MHz)	Outputs				
FSEL0	FSEL1	FSEL2	FSEL3		Ratio	f_{QAx} (MHz)	Ratio	f_{QBx} (MHz)	QFB
0	0	0	0	15 – 25	$f_{REF} * 8$	120 – 200	$f_{REF} * 8$	120 – 200	f_{REF}
0	0	0	1				$f_{REF} * 4$	60 – 100	f_{REF}
0	0	1	0	30 – 50	$f_{REF} * 4$	120 – 200	$f_{REF} * 4$	120 – 200	f_{REF}
0	0	1	1				$f_{REF} * 2$	60 – 100	f_{REF}
0	1	0	0	40 – 66.66	$f_{REF} * 3$	120 – 200	$f_{REF} * 3$	120 – 200	f_{REF}
0	1	0	1				$f_{REF} * 3 \div 2$	60 – 100	f_{REF}
0	1	1	0	30 – 62.5	$f_{REF} * 2$	60 – 125	$f_{REF} * 2$	60 – 125	f_{REF}
0	1	1	1				$f_{REF} * 1$	30 – 75	f_{REF}
1	0	0	0	60 – 100	$f_{REF} * 2$	120 – 200	$f_{REF} * 2$	120 – 200	f_{REF}
1	0	0	1				f_{REF}	60 – 100	f_{REF}
1	0	1	0	15 – 31.25	f_{REF}	15 – 31.25	f_{REF}	15 – 31.25	f_{REF}
1	0	1	1				$f_{REF} \div 2$	7.5 – 15.62	f_{REF}
1	1	0	0	30 – 62.5	f_{REF}	30 – 62.5	f_{REF}	20 – 62.5	f_{REF}
1	1	0	1				$f_{REF} \div 2$	15 – 31.25	f_{REF}
1	1	1	0	60 – 100	f_{REF}	60 – 100	f_{REF}	60 – 100	f_{REF}
1	1	1	1				$f_{REF} \div 2$	30 – 50	f_{REF}

Absolute Maximum Ratings

NOTE: Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These ratings are stress specifications only. Functional operation of product at these conditions or any conditions beyond those listed in the *DC Characteristics* or *AC Characteristics* is not implied. Exposure to absolute maximum rating conditions for extended periods may affect product reliability.

Item	Rating
Supply Voltage, V_{DD}	4.6V
Inputs, V_I	-0.5V to $V_{DD} + 0.5V$
Outputs, V_O	-0.5V to $V_{DD} + 0.5V$
Package Thermal Impedance, θ_{JA}	47.9°C/W (0 lfpm)
Storage Temperature, T_{STG}	-65°C to 150°C

DC Electrical Characteristics

Table 4A. Power Supply DC Characteristics, $V_{DD} = 3.3V \pm 5\%$, $T_A = -40^\circ C$ to $85^\circ C$

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
V_{DD}	Positive Supply Voltage		3.135	3.3	3.465	V
V_{DDA}	Analog Supply Voltage		3.135	3.3	3.465	V
I_{DD}	Power Supply Current				195	mA
I_{DDA}	Analog Supply Current				13	mA

Table 4B. Power Supply DC Characteristics, $V_{DD} = 2.5V \pm 5\%$, $T_A = -40^\circ C$ to $85^\circ C$

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
V_{DD}	Positive Supply Voltage		2.375	2.5	2.625	V
V_{DDA}	Analog Supply Voltage		2.375	2.5	2.625	V
I_{DD}	Power Supply Current				173	mA
I_{DDA}	Analog Supply Current				13	

Table 4C. LVC MOS/LVTTL DC Characteristics, $V_{DD} = 3.3V \pm 5\%$ or $2.5V \pm 5\%$, $T_A = -40^\circ C$ to $85^\circ C$

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
V_{IH}	Input High Voltage	$V_{DD} = 3.465V$	2		$V_{DD} + 0.3$	V
		$V_{DD} = 2.625V$	1.7		$V_{DD} + 0.3$	V
V_{IL}	Input Low Voltage	$V_{DD} = 3.465V$	-0.3		0.8	V
		$V_{DD} = 2.625V$	-0.3		0.7	V
	CLK0, CLK1	$V_{DD} = 3.465V$ or $2.625V$	-0.3		1.3	V
I_{IH}	Input High Current	$V_{DD} = V_{IN} = 3.465V$ or $2.625V$			5	μA
		$V_{DD} = V_{IN} = 3.465V$ or $2.625V$			200	μA
I_{IL}	Input Low Current	$V_{DD} = 3.465V$ or $2.625V$, $V_{IN} = 0V$	-200			μA
		$V_{DD} = 3.465V$ or $2.625V$, $V_{IN} = 0V$	-5			μA
V_{OH}	Output High Voltage	$V_{DD} = 3.465V$, $I_{OH} = -24mA$	2.4			V
		$V_{DD} = 2.625V$, $I_{OH} = -15mA$	1.8			V
V_{OL}	Output Low Voltage	$V_{DD} = 3.465V$, $I_{OL} = 24mA$			0.55	V
		$V_{DD} = 3.465V$, $I_{OL} = 12mA$			0.30	V
		$V_{DD} = 2.625V$, $I_{OL} = 15mA$			0.6	V

Unless otherwise noted, outputs terminated with 50Ω to $V_{DD}/2$.See Parameter Measurement Information section. *Load Test Circuit diagrams*.

AC Electrical Characteristics

Table 5A. AC Characteristics, $V_{DD} = 3.3V \pm 5\%$, $T_A = -40^\circ\text{C}$ to 85°C

Parameter	Symbol	Test Conditions	Minimum	Typical	Maximum	Units
f_{OUT}	Output Frequency		7.5		200	MHz
f_{REF}	Input Frequency		15		100	MHz
BW	PLL Closed Loop Bandwidth			0.8 to 4		MHz
$t(\emptyset)$	Propagation Delay, (Static Phase Offset, CLKx to FB); NOTE 1, 2, 3	$V_{DD} = 3.3V \pm 5\%$; FSEL = 111x	-35		120	ps
		$V_{DD} = 3.3V \pm 5\%$	-35		130	ps
$t_{sk(o)}$	Output Skew; NOTE 1, 2, 3, 4	within bank			50	ps
		bank-to-bank			135	ps
		any output to QFB			315	ps
Δt	Rate of Period Change; NOTE 2	$f_{REF} = 62.5\text{MHz}$, FSEL = 1000			160	ps/ cycle
		FSEL = XXX0		100	280	ps/ cycle
		FSEL = XXX1		200	425	ps/ cycle
$\delta t_{it(cc)}$	Cycle-to-Cycle Jitter; NOTE 2, 3	FSEL3 = 0			150	ps
		FSEL3 = 1			190	ps
Δt_{CYCLE}	Output Clock Period Deviation when switching from primary input to secondary; NOTE 2	$f_{REF} = 62.5\text{MHz}$, FSEL = 1000	-600		700	ps
			-800		800	ps
$\delta t_{it(per)}$	Period Jitter; NOTE 2, 3	FSEL3 = 0			150	ps
		FSEL3 = 1, measured on QBx			150	ps
$\delta t_{it(\emptyset)}$	I/O Phase Jitter, (1σ) ; NOTE 2, 3	FB = 4; FSEL [0:2] = 100 or 111 (1σ)			25	ps
		FB = 6; FSEL [0:2] = 010 (1σ)			25	ps
		FB = 8; FSEL [0:2] = 001, 011 or 110 (1σ)			35	ps
		FB = 16; FSEL [0:2] = 000 or 101 (1σ)			25	ps
t_R / t_F	Output Rise/Fall Time	20% to 80%	250		600	ps
t_{PZL}, t_{PZH}	Output Enable Time; NOTE 2				10	ns
t_{PLZ}, t_{PHZ}	Output Disable Time; NOTE 2				10	ns
t_L	PLL Lock Time; NOTE 2				10	ms
odc	Output Duty Cycle		45	50	55	%

All parameters measured at f_{MAX} unless noted otherwise.

NOTE 1: Defined as the time difference between the input reference clock and the average feedback input signal, when the PLL is locked and the input reference frequency is stable.

NOTE 2: These parameters are guaranteed by characterization. Not tested in production.

NOTE 3: This parameter is defined in accordance with JEDEC Standard 65.

NOTE 4: Defined as skew between outputs at the same supply voltage and with equal load conditions. Measured at $V_{DD}/2$.

Table 5B. AC Characteristics, $V_{DD} = 2.5V \pm 5\%$, $T_A = -40^\circ\text{C}$ to 85°C

Parameter	Symbol	Test Conditions	Minimum	Typical	Maximum	Units
f_{OUT}	Output Frequency		7.5		200	MHz
f_{REF}	Input Frequency		15		100	MHz
BW	PLL Closed Loop Bandwidth			0.8 to 4		MHz
$t(\emptyset)$	Propagation Delay, (Static Phase Offset, CLKx to FB); NOTE 1, 2, 3	$V_{DD} = 3.3V \pm 5\%$; FSEL = 111x	-55		120	ps
		$V_{DD} = 3.3V \pm 5\%$	-55		130	ps
$t_{SK(o)}$	Output Skew; NOTE 1, 2, 3, 4	within bank			50	ps
		bank-to-bank			135	ps
		any output to QFB			280	ps
Δt	Rate of Period Change; NOTE 2	$f_{REF} = 62.5\text{MHz}$, FSEL = 1000			175	ps/ cycle
		FSEL = XXX0			260	ps/ cycle
		FSEL = XXX1			350	ps/ cycle
$f_{JIT(cc)}$	Cycle-to-Cycle Jitter; NOTE 2, 3	FSEL3 = 0			180	ps
		FSEL3 = 1			245	ps
Δt_{CYCLE}	Output Clock Period Deviation when switching from primary input to secondary; NOTE 2	$f_{REF} = 62.5\text{MHz}$, FSEL = 1000	-600		700	ps
			-800		850	ps
$f_{JIT(per)}$	Period Jitter; NOTE 2, 3	FSEL3 = 0			150	ps
		FSEL3 = 1, measured on QBx			150	ps
$f_{JIT(\emptyset)}$	I/O Phase Jitter, (1σ) ; NOTE 2, 3	FB = 4; FSEL [0:2] = 100 or 111 (1σ)			30	ps
		FB = 6; FSEL [0:2] = 010 (1σ)			40	ps
		FB = 8; FSEL [0:2] = 001, 011 or 110 (1σ)			25	ps
		FB = 16; FSEL [0:2] = 000 or 101 (1σ)			30	ps
t_R / t_F	Output Rise/Fall Time	20% to 80%	250		600	ps
t_{PZL}, t_{PZH}	Output Enable Time; NOTE 2				10	ns
t_{PLZ}, t_{PHZ}	Output Disable Time; NOTE 2				10	ns
t_L	PLL Lock Time; NOTE 2				10	ms
odc	Output Duty Cycle		45	50	55	%

All parameters measured at f_{MAX} unless noted otherwise.

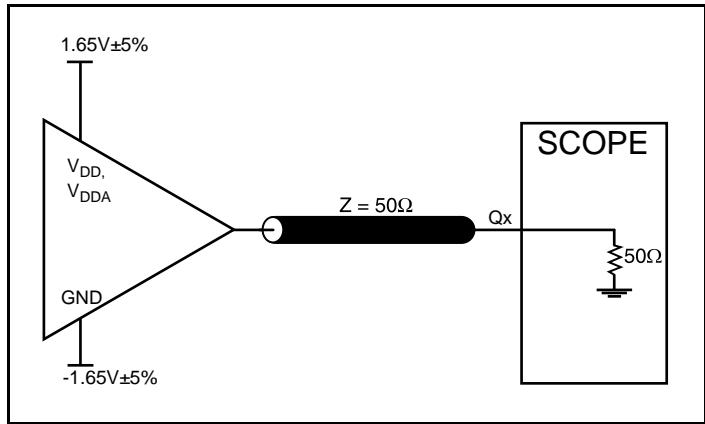
NOTE 1: Defined as the time difference between the input reference clock and the average feedback input signal, when the PLL is locked and the input reference frequency is stable.

NOTE 2: These parameters are guaranteed by characterization. Not tested in production.

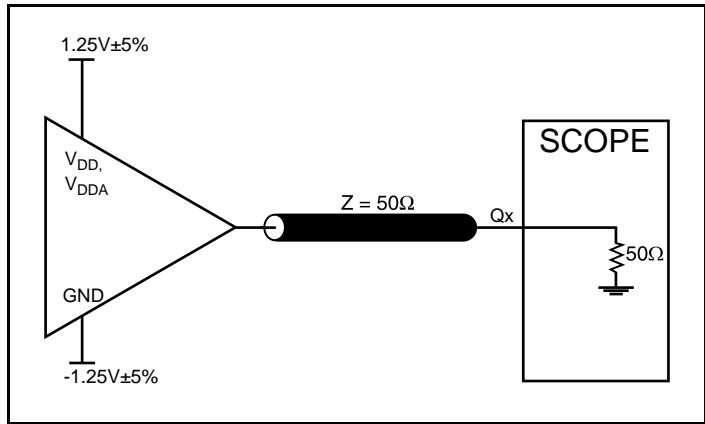
NOTE 3: This parameter is defined in accordance with JEDEC Standard 65.

NOTE 4: Defined as skew between outputs at the same supply voltage and with equal load conditions. Measured at $V_{DD}/2$.

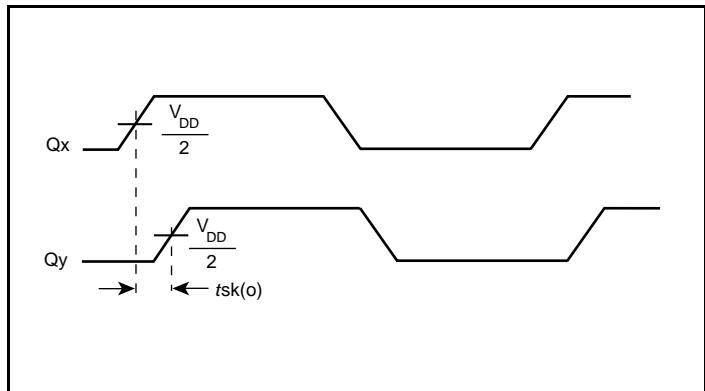
Parameter Measurement Information



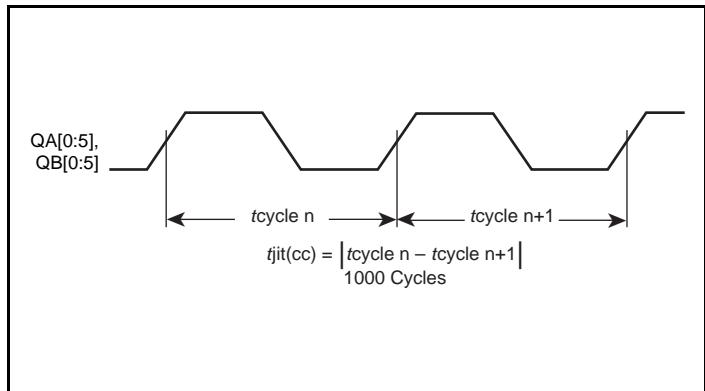
3.3V Output Load AC Test Circuit



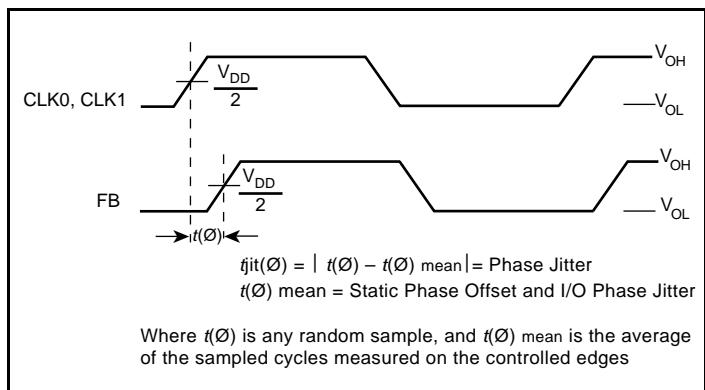
2.5V Output Load AC Test Circuit



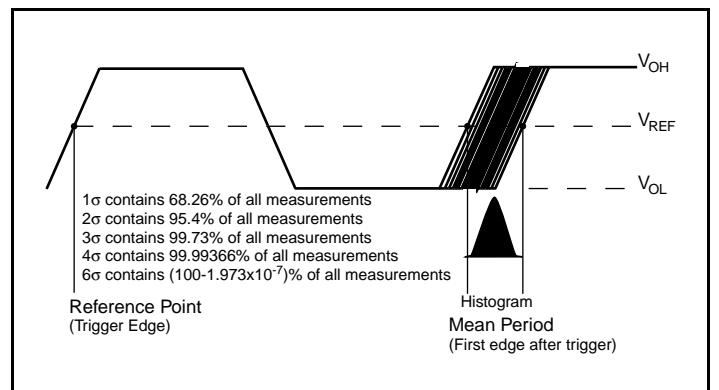
Output Skew



Cycle-to-Cycle Jitter

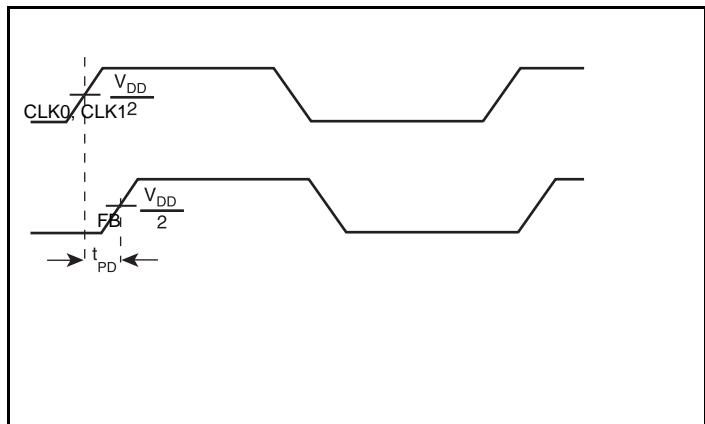


Input/Output Phase Jitter

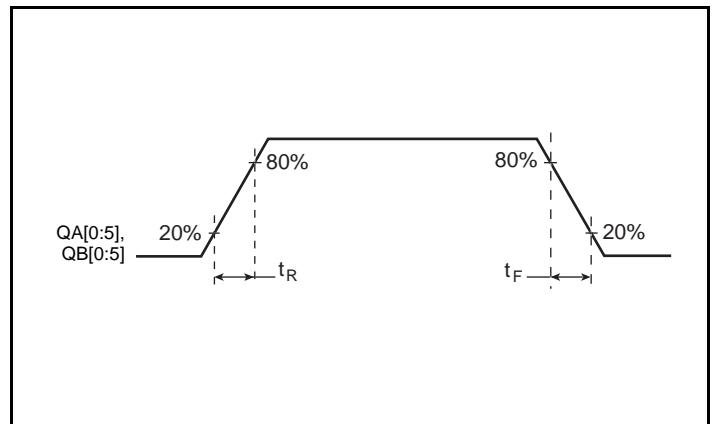


Period Jitter

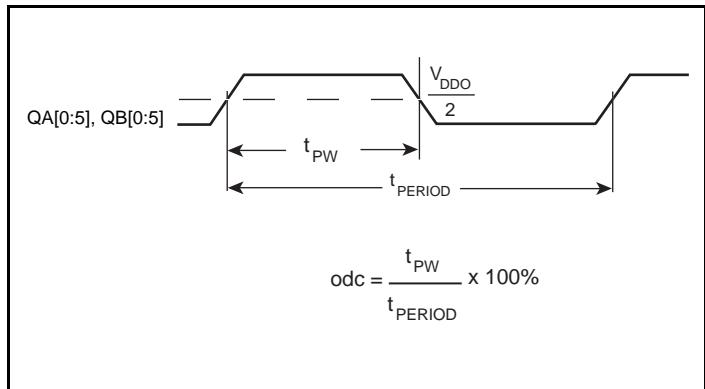
Parameter Measurement Information, continued



Propagation Delay



Output Rise/Fall Time



Output Duty Cycle/Pulse Width/Period

Application Information

CLOCK REDUNDANCY AND REFERENCE SELECTION

The 879893 accepts two LVCMS/LVTTI single ended input clocks, CLK0 and CLK1, for the purpose of redundancy. Only one of these clocks can be selected at any given time for use as the reference. The clock that is used by default as the reference is referred to as the primary clock, while the remaining clock is the redundant or secondary clock. Input signal REF_SEL determines which input is to be used as the primary and which is to be used as the secondary. When REF_SEL is driven HIGH, the primary clock input is CLK1, otherwise an internal pull down pulls this input LOW so that the primary clock input is CLK0. The output signal CLK_IND indicates which clock input is being used as the reference (LOW = CLK0, HIGH = CLK1), and will initially be at the same level as REF_SEL.

FAILURE DETECTION AND ALARM SIGNALING

Within the 879893 device, CLK0 and CLK are continuously monitored for failures. A failure on either of these clocks is detected when one of the clock signals is stuck HIGH or LOW for at least 1 period. Upon detection of a failure, the corresponding alarm signal, nALARM0 or nALARM1, is latched LOW. A HIGH-to-LOW transition on input signal nALARM_RST causes the alarm outputs to be reset HIGH, and the primary clock input is selected as the reference clock. Otherwise, an internal pull-up holds nALARM_RST HIGH, and the IDCS flags remain unchanged. If n_ALARM_RST is asserted when both of the alarm flag outputs are LOW, CLK0 is selected as the reference input. The device's internal PLL is able to maintain phase/frequency alignment, and lock with the input as long as the input used as the reference clock does not fail.

MANUAL CLOCK SWITCHING

When input signal nMAN/A is driven LOW, the primary clock, as selected by REF_SEL, is always used as the reference, even when a clock failure is detected at the reference. In order to switch between CLK0 and CLK1 as the primary clock, the level on REF_SEL must be driven to the appropriate level. When the level on REF_SEL is changed, the selection of the new primary clock will take place, and CLK_IND will be updated to indicate which clock is now supplying reference. This process serves as a manual safety mechanism to protect the stability of the PLL when a failure occurs on the reference.

DYNAMIC CLOCK SWITCHING

When input signal nMAN/A is not driven LOW, an internal pull-up pulls it HIGH so that Intelligent Dynamic Clock Switching (IDCS) is enabled. If IDCS is enabled, once a failure occurs on the primary clock, the 879893 device will automatically deselect the primary clock as the reference and multiplex in the secondary clock, but only if it is valid and has no failures. When a successful switch from primary to secondary has been accomplished, CLK_IND will be updated to indicate the new reference. This process serves as an automatic safety mechanism to protect the stability of the PLL when a failure occurs on the reference.

OUTPUT TRANSITIONING

After a successful manual or IDCS initiated clock switch, the 879893's internal PLL will begin slewing to phase/frequency alignment, and will eventually achieve lock with the new input with minimal phase disturbance at the outputs.

MASTER RESET OPERATION

Applying logic HIGH to the nOE/MR input resets the internal dividers of the 879893 and disables the outputs QA0:QA5 and QB0:QB5 in high-impedance state. Logic LOW state at the nOE/MR input enables the outputs and internal dividers.

RECOMMENDED POWER-UP SEQUENCE

1. Hold nOE/MR HIGH, drive nMAN/A LOW, and drive REF_SEL to the desired value during power up in order to reset internal dividers, disable the outputs in high-impedance state (nOE/MR = HIGH), select manual switching mode, and select the primary input clock.
2. Once powered up, assuming a stable clock free of failures is present at the primary input, the PLL will begin phase/frequency slewing as it attempts to achieve lock with the input reference clock.
3. Transition nALARM_RST HIGH-to-LOW to reset nALARM0 and nALARM1 alarm flag outputs.
4. (Optional) Drive nMAN/A HIGH to enable IDCS mode.

ALTERNATE POWER-UP SEQUENCE

If both input clocks are valid before power up, the device may be powered up in IDCS mode.

1. During power up, select the desired primary clock input by REF_SEL and hold nOE/MR at logic HIGH level to reset the internal dividers and to disable the outputs QA0:QA5 and QB0:QB5 in high-impedance state. Logic high level at the nMAN/A input enables the IDCS mode. An internal bias resistor will pull the nMAN/A input to logic high level if nMAN/A is left open.
2. Once powered up, the PLL will begin phase/frequency slewing as it attempts to achieve lock with the input reference clock.
3. Transition nALARM_RST HIGH-to-LOW to reset nALARM0 and nALARM1 alarm flag outputs.

Recommendations for Unused Input and Output Pins

Inputs:

CLK Inputs

For applications not requiring the use of a clock input, it can be left floating. Though not required, but for additional protection, a $1\text{k}\Omega$ resistor can be tied from the CLK input to ground.

LVC MOS Control Pins

All control pins have internal pull-ups or pull-downs; additional resistance is not required but can be added for additional protection. A $1\text{k}\Omega$ resistor can be used.

Outputs:

LVC MOS Outputs

All unused LVC MOS output can be left floating. There should be no trace attached.

Power Supply Filtering Technique

As in any high speed analog circuitry, the power supply pins are vulnerable to random noise. To achieve optimum jitter performance, power supply isolation is required. The 879893 provides separate power supplies to isolate any high switching noise from the outputs to the internal PLL. V_{DD} and V_{DDA} should be individually connected to the power supply plane through vias, and $0.01\mu\text{F}$ bypass capacitors should be used for each pin. *Figure 1* illustrates this for a generic V_{DD} pin and also shows that V_{DDA} requires that an additional 10Ω resistor along with a $10\mu\text{F}$ bypass capacitor be connected to the V_{DDA} pin.

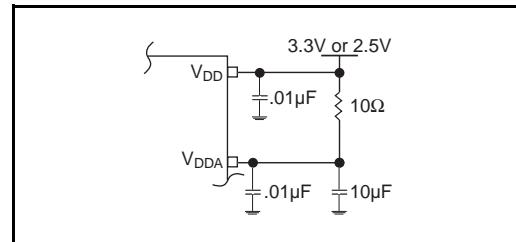


Figure 1. Power Supply Filtering

Schematic Example

Figure 2 shows a schematic example of the 879893. In this example, the CLK1 input is selected as primary. Both CLK0 and CLK1 inputs are driven by LVCMS drivers. For the LVCMS outputs, series termination is shown in this example. Additional LVCMS termination approaches are shown in the LVCMS Termination Application Note. In this example, feedback trace is assumed to be a long trace. The series termination near the QFB

pin is required. If the feedback trace is short, series termination is not required. If this device is also used as a zero delay buffer, the application note ZDB Delay Affected by Feedback Trace provides additional information. For the power pins, it is recommended to have at least one decoupling capacitor per power pin. The decoupling capacitors should be physically located near the power pins.

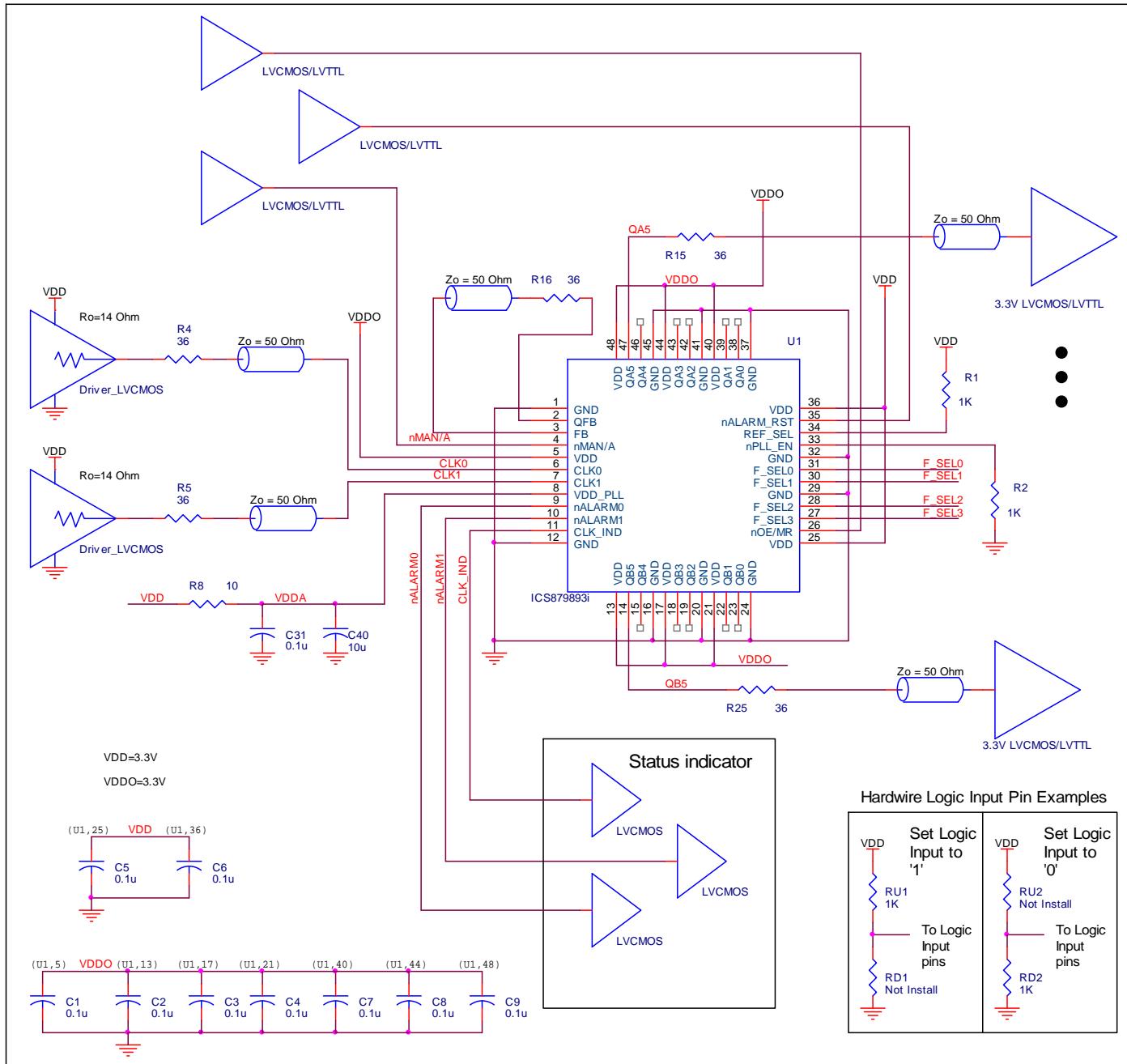


Figure 2. 879893 Schematic Example

Reliability Information

Table 6. θ_{JA} vs. Air Flow Table for a 48 Lead LQFP

θ_{JA} vs. Air Flow			
Linear Feet per Minute	0	200	500
Single-Layer PCB, JEDEC Standard Test Boards	67.8°C/W	55.9°C/W	50.1°C/W
Multi-Layer PCB, JEDEC Standard Test Boards	47.9°C/W	42.1°C/W	39.4°C/W

NOTE: Most modern PCB design use multi-layered boards. The data in the second row pertains to most designs.

Transistor Count

The transistor count for 879893 is: 4615

Package Outline and Package Dimensions

Package Outline - Y Suffix for 48 Lead LQFP

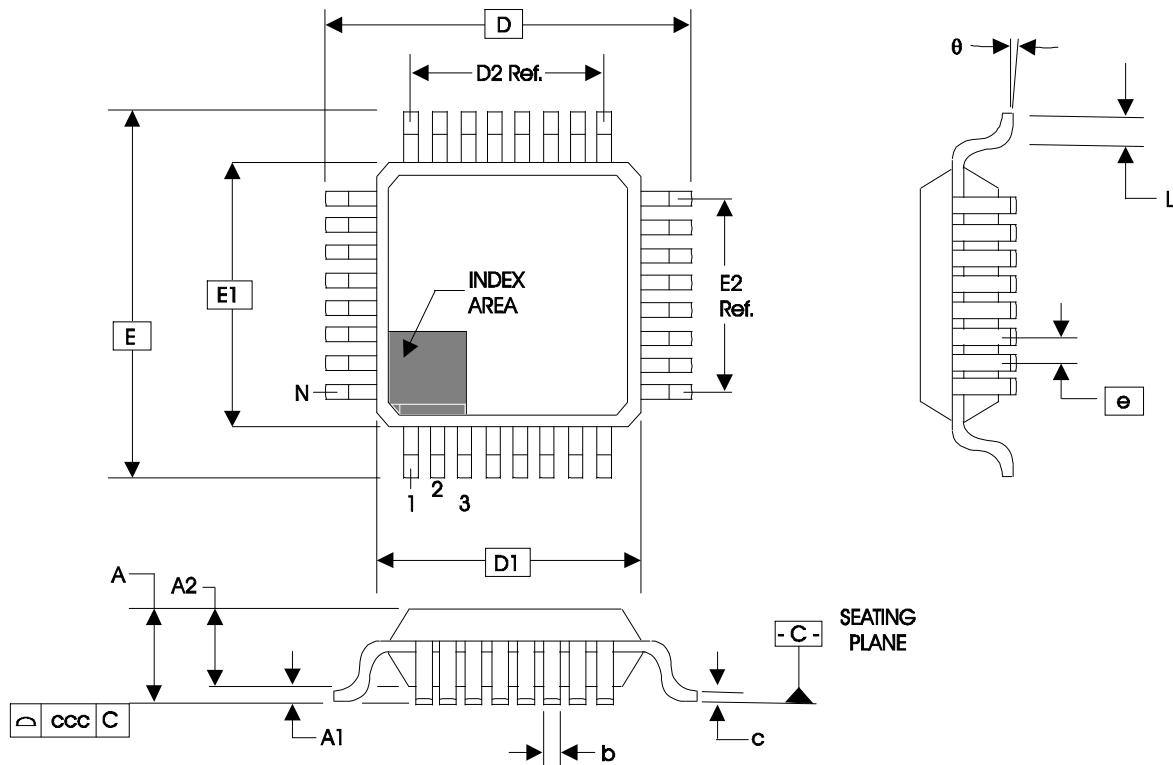


Table 7. Package Dimensions for 48 Lead LQFP

JEDEC Variation: ABC - HD All Dimensions in Millimeters			
Symbol	Minimum	Nominal	Maximum
N		48	
A			1.60
A1	0.05	0.10	0.15
A2	1.35	1.4	1.45
b	0.17	0.22	0.27
c	0.09	0.15	0.20
D & E	9.00 Basic		
D1 & E1	7.00 Basic		
D2 & E2	5.50 Ref.		
e	0.50 Basic		
L	0.45	0.60	0.75
θ	0°		7°
ccc			0.08

Reference Document: JEDEC Publication 95, MS-026

Ordering Information

Table 8. Ordering Information

Part/Order Number	Marking	Package	Shipping Packaging	Temperature
879893AYILF	ICS879893AIL	"Lead-Free" 48 Lead LQFP	Tray	-40°C to 85°C
879893AYILFT	ICS879893AIL	"Lead-Free" 48 Lead LQFP	Tape & Reel	-40°C to 85°C

NOTE: Parts that are ordered with an "LF" suffix to the part number are the Pb-Free configuration and are RoHS compliant.

Revision History Sheet

Rev	Table	Page	Description of Change	Date
A		12	Updated Schematic Example text and diagram.	2/10/05
A	T8	1 11 15	Features Section - added lead-free bullet. <i>Added Recommendations for Unused Input and Output Pins and Power Supply Filtering Techniques</i> Sections. Ordering Information Table - added lead-free Part/Order Number, Marking and Note. Updated datasheet format.	7/8/08
A	T8	16	Ordering Information - removed leaded devices. Updated data sheet format.	7/21/15
A		1	Product Discontinuation Notice - Last time buy expires November 2, 2016. PDN# CQ-15-05.	11/6/15
B			Datasheet is obsolete per PDN# CQ-15-05.	1/10/17

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